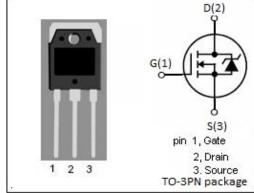


isc N-Channel MOSFET Transistor

2SK750

DESCRIPTION

- Drain Current –I_D= 20A@ T_C=25 °C
- Drain Source Voltage-
 - : V_{DSS}= 100V(Min)
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

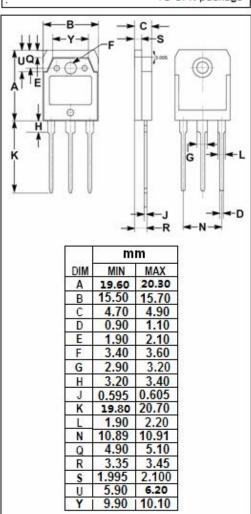


APPLICATIONS

· High speed power switching



SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	100	V
V _G s	Sate-Source Voltage ±20		V
ID	Drain Current-continuous@ TC=25℃	20	Α
P _{tot}	Total Dissipation@TC=25℃	ion@TC=25℃ 100	
Tj	Max. Operating Junction Temperature	150	$^{\circ}$ C
T _{stg}	Storage Temperature Range	-55~150	°C





isc N-Channel Mosfet Transistor

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• ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0; I _D = 10mA	100			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =10 V _{GS} ; I _D =1mA	1.0		5.0	V
R _{DS(on)}	Drain-Source On-stage Resistance	V _{GS} =10V; I _D = 10A			0.08	Ω
Igss	Gate Source Leakage Current	V _{GS} = ±16V;V _{DS} = 0			±10	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =80V; V _{GS} = 0			250	uA
V _{SD}	Diode Forward Voltage	I _F =10A; V _{GS} =0		1.2		V



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